

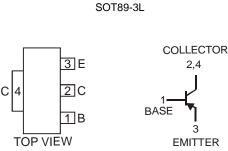


2DB1188P/Q/R

PNP SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (2DD1766)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Mechanical Data
- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.072 grams (approximate)



Schematic and Pin Configuration

Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-32	V
Emitter-Base Voltage	V _{EBO}	-5	V
Peak Pulse Current	I _{CM}	-3	A
Continuous Collector Current	lc	-2	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ $T_A = 25^{\circ}C$	PD	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ $T_A = 25^{\circ}C$	$R_{\theta JA}$	125	°C/W
Operating and Storage Temperature Range	Tj, T _{STG}	-55 to +150	°C

Electrical Characteristics $@T_A = 25^{\circ}C$ unless otherwise specified

Charao	teristic	Symbol	Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTICS (N	ote 4)						•
Collector-Base Breakdown Vo	ltage	V _{(BR)CBO}	-40	_	_	V	$I_{C} = -50 \mu A$, $I_{E} = 0$
Collector-Emitter Breakdown Voltage		V _{(BR)CEO}	-32	_	_	V	$I_{\rm C} = -1 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage		V _{(BR)EBO}	-5	_	_	V	$I_E = -50 \mu A, I_C = 0$
Collector Cut-Off Current		ICBO	_		-1	μΑ	$V_{CB} = -20V, I_E = 0$
Emitter Cut-Off Current		I _{EBO}	_		-1	μΑ	$V_{EB} = -4V, I_{C} = 0$
ON CHARACTERISTICS (No	te 4)						
Collector-Emitter Saturation V	oltage	V _{CE(SAT)}	_	-0.35	-0.8	V	$I_{\rm C} = -2A, I_{\rm B} = -0.2A$
DC Current Gain	2DB1188P	h _{FE}	82		180	_	
	2DB1188Q		120	_	270	_	$V_{CE} = -3V, I_{C} = -0.5A$
	2DB1188R		180	_	390	_]
SMALL SIGNAL CHARACTE	RISTICS						
Transition Frequency		f _T	_	120	_	MHz	$I_E = 0.1A, V_{CE} = -5V,$ f = 30MHz
Output Capacitance		C _{ob}		20	_	pF	$V_{CB} = -10V, I_E = 0,$ f = 1MHz

Notes: 1. No purposefully added lead.

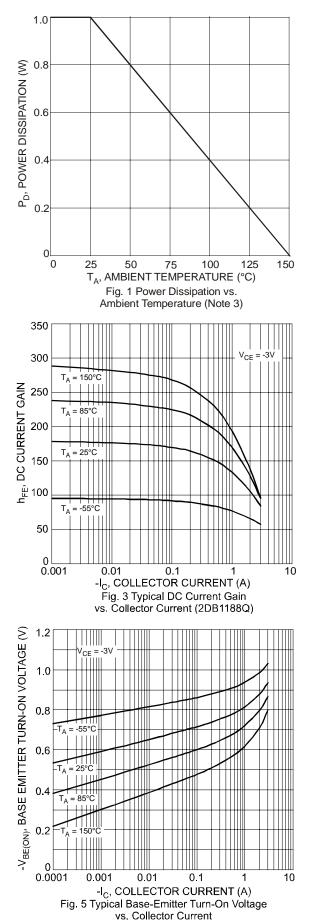
2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

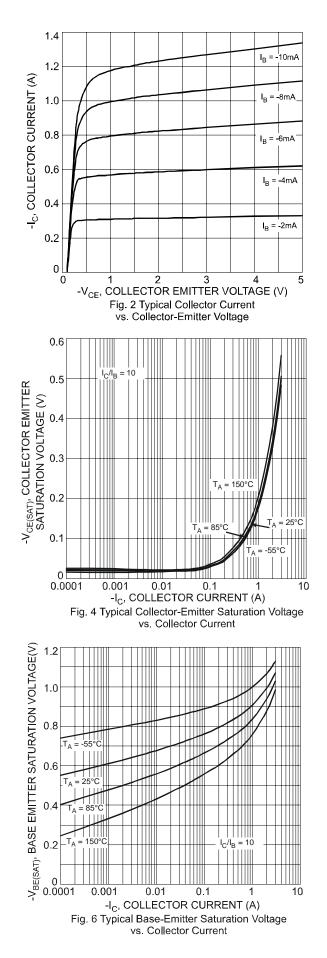
3. Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can

be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

4. Measured under pulsed conditions. Pulse width = 300 $\mu s.$ Duty cycle ${\leq}2\%.$

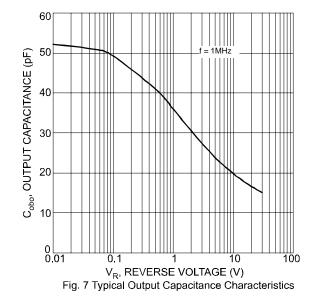


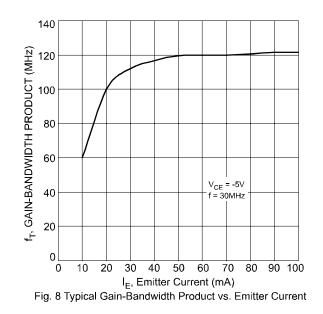










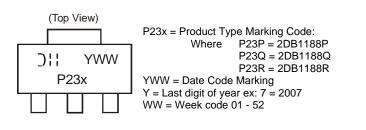


Ordering Information (Note 5)

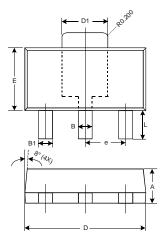
Device	Packaging	Shipping
2DB1188P-13	SOT89-3L	2500/Tape & Reel
2DB1188Q-13	SOT89-3L	2500/Tape & Reel
2DB1188R-13	SOT89-3L	2500/Tape & Reel

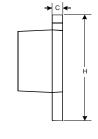
Notes: 5. For packaging details, go to our website at http://www.diodes.com/ap02007.pdf.

Marking Information



Package Outline Dimensions

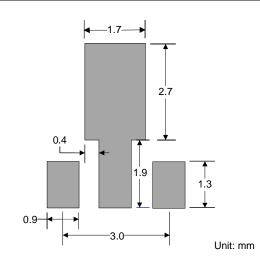




SOT89-3L					
Dim	Min	Мах	Тур		
Α	1.40	1.60	1.50		
В	0.45	0.55	0.50		
B1	0.37	0.47	0.42		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.50	1.70	1.60		
E	2.40	2.60	2.50		
е	_	_	1.50		
Н	3.95	4.25	4.10		
L	0.90	1.20	1.05		
All Dimensions in mm					



Suggested Pad Layout



IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.